INTEGRATED CIRCUITS

DATA SHEET

74F260Dual 5-input NOR gate

Product specification

1988 Nov 29

IC15 Data Handbook





Dual 5-input NOR gate

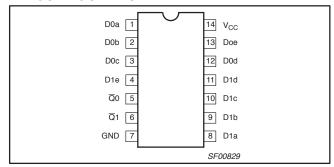
74F260

TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
74F260	3.5ns	6mA

ORDERING INFORMATION

DESCRIPTION	COMMERCIAL RANGE $V_{CC} = 5V \pm 10\%$, $T_{amb} = 0$ °C to +70°C	PKG DWG #
14-pin plastic DIP	N74F260N	SOT27-1
14-pin plastic SO	N74F260D	SOT108-1

PIN CONFIGURATION

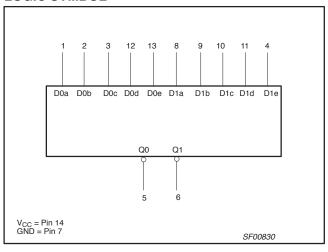


INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

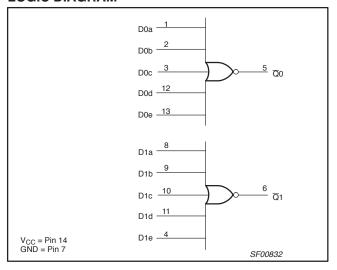
PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW		
Dna, Dnb, Dnc, Dnd, Dne	Data inputs	1.0/1.0	20μA/0.6mA		
Q0, Q1	Data outputs	50/33	1.0mA/20mA		

NOTE: One (1.0) FAST unit load is defined as: 20μA in the High state and 0.6mA in the Low state.

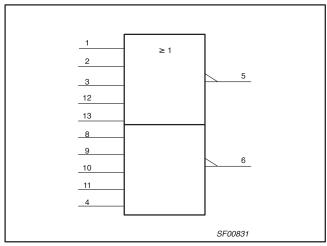
LOGIC SYMBOL



LOGIC DIAGRAM



IEC/IEEE SYMBOL



FUNCTION TABLE

		INPUTS			OUTPUT
Dna	Dnb	Dnc	Dnd	Dne	Qn
Н	Х	Х	Х	Х	L
Х	Н	Х	Х	Х	L
Х	Х	Н	Х	Х	L
Х	Х	Х	Н	Х	L
Х	Х	Х	Х	Н	L
L	L	L	L	L	Н

H = High voltage level L = Low voltage level

X = Don't care

Philips Semiconductors Product specification

Dual 5-input NOR gate

74F260

ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limits set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	-0.5 to +7.0	V
V _{IN}	Input voltage	-0.5 to +7.0	V
I _{IN}	Input current	−30 to +5	mA
V _{OUT}	Voltage applied to output in High output state	–0.5 to V _{CC}	V
l _{OUT}	Current applied to output in Low output state	40	mA
T _{amb}	Operating free-air temperature range	0 to +70	°C
T _{stg}	Storage temperature range	-65 to +150	°C

RECOMMENDED OPERATING CONDITIONS

CVMDOL	PARAMETER		LIMITS		LINUT
SYMBOL	PARAMETER	MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	4.5	5.0	5.5	V
V _{IH}	High-level input voltage	2.0			V
V _{IL}	Low-level input voltage			0.8	V
I _{IK}	Input clamp current			-18	mA
I _{OH}	High-level output current			-1	mA
I _{OL}	Low-level output current			20	mA
T _{amb}	Operating free-air temperature range	0		+70	°C

DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

						LIMITS		
SYMBOL	PARAMETER		TEST CONDITIONS	MIN	TYP NO TAG	MAX	UNIT	
V	Lligh lovel output voltage		$V_{CC} = MIN, V_{IL} = MAX$	= MAX ±10%V _{CC} 2.5				V
V _{OH}	High-level output voltage		V _{IH} = MIN, I _{OH} = MAX	±5%V _{CC}	2.7	3.4		V
V	Low lovel output voltage		$V_{CC} = MIN, V_{IL} = MAX$	±10%V _{CC}		0.30	0.50	V
V _{OL}	Low-level output voltage		V _{IH} = MIN, I _{OL} = MAX	±5%V _{CC}		0.30	0.50	V
V _{IK}	Input clamp voltage		$V_{CC} = MIN, I_I = I_{IK}$		-0.73	-1.2	V	
I _I	Input current at maximum input v	oltage/	$V_{CC} = MAX, V_I = 7.0V$			100	μΑ	
I _{IH}	High-level input current		$V_{CC} = MAX, V_I = 2.7V$			20	μΑ	
I _{IL}	Low-level input current		$V_{CC} = MAX, V_I = 0.5V$			-0.6	mA	
los	Short-circuit output currentNO TA	G	V _{CC} = MAX	-60		-150	mA	
	Supply current (total)		V -MAY	V _{IN} =GND		4.6	6.5	mA
Icc	Supply current (total)	I _{CCL}	V _{CC} = MAX	V _{IN} =4.5V		7.3	9.5	mA

NOTES:

1988 Nov 29

^{1.} For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

All typical values are at V_{CC} = 5V, T_{amb} = 25°C.
 Not more than one output should be shorted at a time. For testing I_{OS}, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

Philips Semiconductors Product specification

Dual 5-input NOR gate

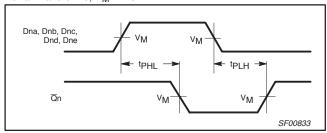
74F260

AC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITION	V_{CC} = +5.V T_{amb} = +25°C C_L = 50pF, R_L = 500 Ω			V _{CC} = +5 T _{amb} = 0°C C _L = 50pF,	UNIT	
			MIN	TYP	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay Dna, Dnb, Dnc, Dnd, Dne to Qn	Waveform NO TAG	2.5 1.5	4.0 2.5	5.5 4.0	2.0 1.0	6.5 4.5	ns

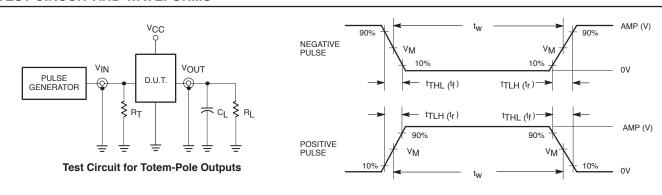
AC WAVEFORM

For all waveforms, $V_M = 1.5V$.



Waveform 1. For Inverting Outputs

TEST CIRCUIT AND WAVEFORMS



DEFINITIONS:

R_L = Load resistor;

see AC ELECTRICAL CHARACTERISTICS for value.

C_L = Load capacitance includes jig and probe capacitance; see AC ELECTRICAL CHARACTERISTICS for value.

Termination resistance should be equal to Z_{OUT} of $R_T =$ pulse generators.

Input Pulse Definition

family	INP	INPUT PULSE REQUIREMENTS												
	amplitude	V_{M}	rep. rate	t _w	t _{TLH}	t _{THL}								
74F	3.0V	1.5V	1MHz	500ns	2.5ns	2.5ns								

SF00006

1988 Nov 29

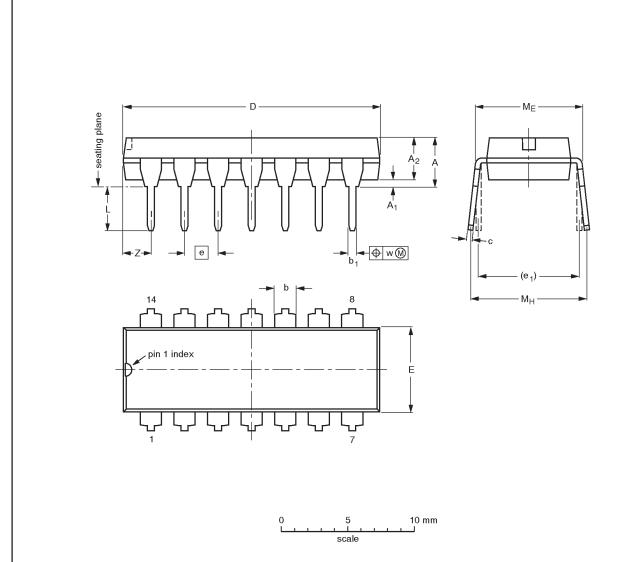
Philips Semiconductors Product specification

Dual 5-input NOR gate

74F260

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT27-1	050G04	MO-001AA				92-11-17 95-03-11	

1988 Nov 29 5

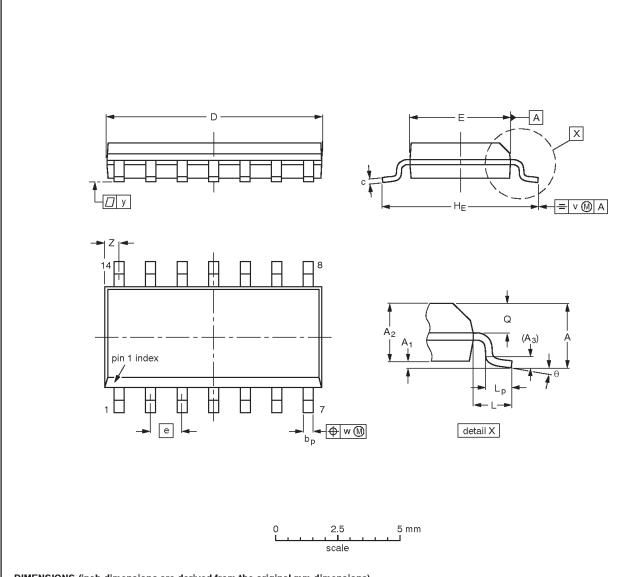
Philips Semiconductors Product specification

Dual 5-input NOR gate

74F260

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075		0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	o°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

	OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
		IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
	SOT108-1	076E06S	MS-012AB				95-01-23 97-05-22

1988 Nov 29 6 Philips Semiconductors Product specification

Dual 5-input NOR gate

74F260

NOTES

1988 Nov 29 7

Philips Semiconductors Product specification

Dual 5-input NOR gate

74F260

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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